



DMT10H072LFDF

D

S

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
1001/	$62m\Omega @ V_{GS} = 10V$	4A
100V	80mΩ @ V _{GS} = 6V	3.5A

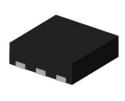
Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

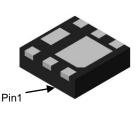
Applications

- **Power Management Functions**
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.

U-DFN2020-6 (Type F)



Top View



Bottom View

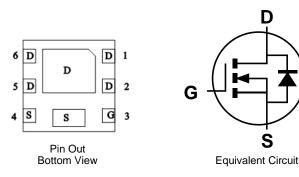


Features and Benefits

- 0.6mm Profile Ideal for Low Profile Applications
- PCB Footprint of 4mm²
- Low On-Resistance
- 100% Unclamped Inductive Switching (UIS) Test in Production -Ensures More Reliable and Robust End Application
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @4)
- Weight: 0.0065 grams (Approximate)





7							
	Part Number	Case	Quantity Per Reel				
	DMT10H072LFDF-7	U-DFN2020-6 (Type F)	3,000				
	DMT10H072LFDF-13	U-DFN2020-6 (Type F)	10,000				
Notes:	Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.						

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

U-DFN2020-6 (Type F)



 $\begin{array}{l} 72 = \mbox{Product Type Marking Code} \\ \mbox{YM} = \mbox{Date Code Marking} \\ \mbox{Y} = \mbox{Year (ex: G = 2019)} \\ \mbox{M} = \mbox{Month (ex: 9 = September)} \end{array}$

Date Code Key			_									
Year	2019	20)20	2021	2022	20	023	2024	2025	20	026	2027
Code	G		Н		J		K	L	М		Ν	0
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

U-DFN2020-6 (Type F)



72 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 9 = 2019) W = Week (ex: a = week 27; z represents week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key									
Year	2019	2020	2021	2022	2023	2024	2025	2026	2027
Code	9	0	1	2	3	4	5	6	7
Week	1-26			27-52			53		
Code	A-Z			a-z			Z		
Internal Code	Sun	Mon		Tue	Wed	Thu		Fri	Sat
Code	Т	U		V	W	Х		Y	7



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		V _{DSS}	100	V
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current, V _{GS} = 10V (Note 6)	T _A = +25°C T _A = +70°C	ID	4 3.2	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	·	I _{DM}	22	А
Maximum Body Diode Continuous Current		ls	1.6	А
Avalanche Current, L = 0.1mH (Note 9)	I _{AS}	6	А	
Avalanche Energy, L = 0.1mH (Note 9)		E _{AS}	1.8	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Dower Dissinction (Note 5)	T _A = +25°C	D	0.8	10/
Total Power Dissipation (Note 5)	T _A = +70°C	PD	0.5	W
Thermal Resistance, Junction to Ambient (Note 5)		$R_{ extsf{ heta}JA}$	149	°C/W
Total Dower Dissinction (Note 6)	T _A = +25°C		1.8	W
Total Power Dissipation (Note 6)	T _A = +70°C	PD	1.1	
Thermal Resistance, Junction to Ambient (Note 6)		$R_{\theta JA}$	71	°C/W
Thermal Resistance, Junction to Case (Note 6)	R _{θJC}	13	C/VV	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Ok and a tania tia	0. multi a l	Min	T	Maria	11	Tast Oswalitism
Characteristic OFF CHARACTERISTICS (Note 7)	Symbol	Min	Тур	Max	Unit	Test Condition
	D) (100	1		M	
Drain-Source Breakdown Voltage	BV _{DSS}	100	—		V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	$V_{\rm DS} = 80 \text{V}, V_{\rm GS} = 0 \text{V}$
Gate-Source Leakage	I _{GSS}	_		±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)			1			
Gate Threshold Voltage	V _{GS(TH)}	1	—	3	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
		-	47	62	mΩ	$V_{GS} = 10V, I_D = 4.5A$
Static Drain-Source On-Resistance	R _{DS(ON)}		54	80	11152	$V_{GS} = 6V, I_D = 4A$
			64	110	mΩ	$V_{GS} = 4.5V, I_D = 2.6A$
Diode Forward Voltage	V _{SD}		0.7	1.0	V	$V_{GS} = 0V, I_{S} = 1A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		228	_	pF	
Output Capacitance	Coss	_	89.3	_	pF	V _{DS} = 50V, V _{GS} = 0V, f = 1MHz
Reverse Transfer Capacitance	Crss	_	2.5	—	pF	
Gate Resistance	Rg	_	8.2	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	2.5	_	nC	
Total Gate Charge (V _{GS} = 10V)	Qg	_	4.5	—	nC	
Gate-Source Charge	Q _{gs}	_	0.6	—	nC	$V_{DS} = 50V, I_D = 4.5A$
Gate-Drain Charge	Q _{gd}	_	1.3	_	nC	
Turn-On Delay Time	t _{D(ON)}	—	3.0	—	ns	
Turn-On Rise Time	t _R		3.1	_	ns	$V_{DS} = 50V, R_{L} = 11\Omega$
Turn-Off Delay Time	t _{D(OFF)}		12.3	_	ns	$V_{GS} = 10V, R_{GEN} = 3\Omega$
Turn-Off Fall Time	t _F		4.3	_	ns	
Reverse Recovery Time	t _{RR}		22.9	_	ns	
Reverse Recovery Charge	Q _{RR}		45.2	_	nC	I _F = 4.5A, di/dt = 300A/µs

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

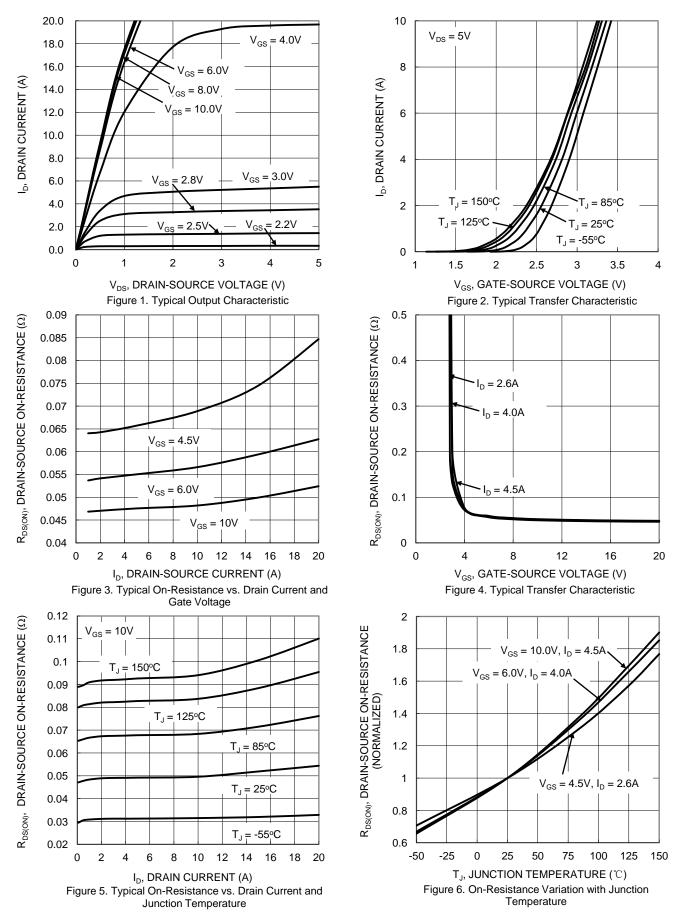
7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.

9. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

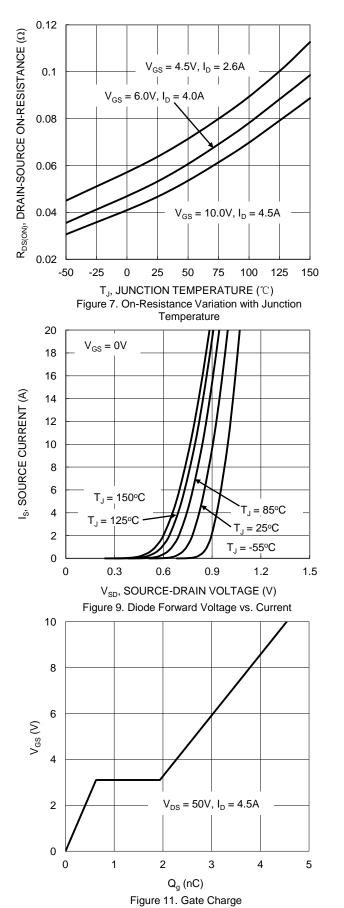


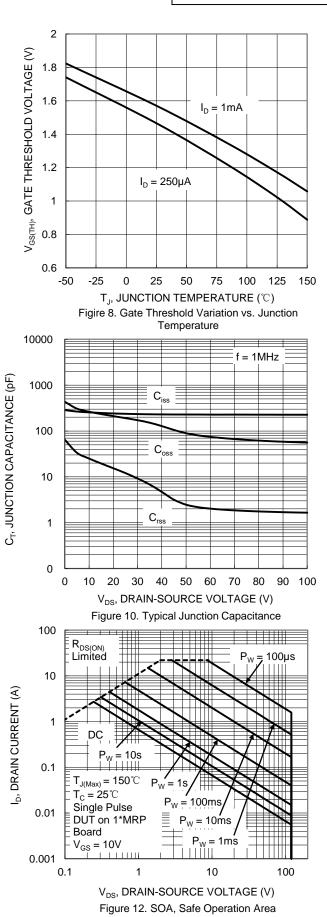
DMT10H072LFDF



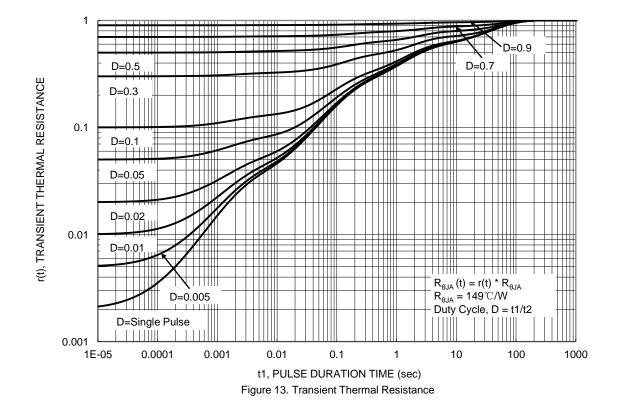
DMT10H072LFDF Datasheet number: DS38574 Rev. 5 - 2









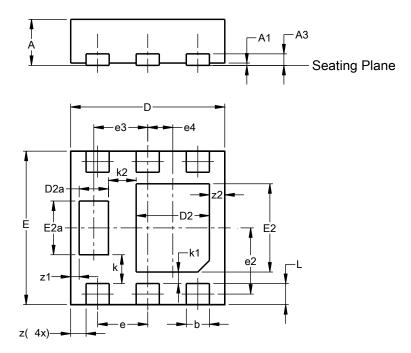




Package Outline Dimension

Please see http://www.diodes.com/package-outlines.html for the latest version.

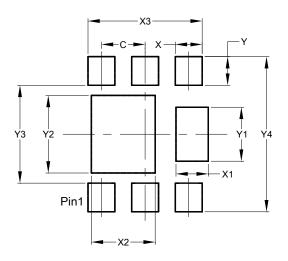
U-DFN2020-6 (Type F)



U-DFN2020-6									
	(Type F)								
Dim	Min	Max	Тур						
Α	0.57	0.63	0.60						
A1	0.00	0.05	0.03						
A3	-	-	0.15						
b	0.25	0.35	0.30						
D	1.95	2.05	2.00						
D2	0.85	1.05	0.95						
D2a	0.33	0.43	0.38						
Е	1.95	2.05	2.00						
E2	1.05	1.25	1.15						
E2a	0.65	0.75	0.70						
е	0.65 BSC								
e2	C).863 BS	SC						
e3		0.70 BS	С						
e4	C).325 BS	SC						
k		0.37 BS	С						
k1		0.15 BS	С						
k2		0.36 BS	С						
L	0.225	0.325	0.275						
z		0.20 BS	С						
z1	C).110 BS	SC						
z2		0.20 BS	С						
All C	Dimens	ions in	mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



U-DFN2020-6 (Type F)

r	
Dimensions	Value
Dimensions	(in mm)
С	0.650
Х	0.400
X1	0.480
X2	0.950
X3	1.700
Y	0.425
Y1	0.800
Y2	1.150
Y3	1.450
Y4	2.300



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2019, Diodes Incorporated

www.diodes.com

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Diodes Incorporated manufacturer:

Other Similar products are found below :

004419CB 069117AB 1.5KE15A-T 1.5KE15CA-T 1.5KE200A-T 1.5KE20CA-T 1.5KE24A-T 1.5KE250CA-T 1.5KE27CA-T 1.5KE30A-T 1.5KE30CA-T 1.5KE33A-T 1.5KE350A-T 1.5KE36CA-T 1.5KE47A-T 1.5KE47CA-T 1.5KE51CA-T 1.5KE62A-T 1.5KE68A-T 1.5KE68CA 1.5KE68CA-T 1.5KE7V5A-T 1.5KE82CA-T 1.5KE9V1A-T 1N4001G-T 1N4001-T 1N4002 1N4002G-T 1N4002-T 1N4003G-T 1N4003-T 1N4004 1N4004G-T 1N4004-T 1N4005-B 1N4005G-T 1N4005-T 1N4005-TR 1N4006-B 1N4006G-T 1N4006-T 1N4007G-T 1N4007-T 1N4148-T 1N4148W-13-F 1N4148W-7-F 1N4148WQ-13-F 1N4148WQ-7-F 1N4148WS-13-F 1N4148WS-7-F